

BLF7G27L-90P; BLF7G27LS-90P

Power LDMOS transistor

Rev. 2 — 10 November 2011

Product data sheet

1. Product profile

1.1 General description

90 W LDMOS power transistor for base station applications at frequencies from 2500 MHz to 2700 MHz.

Table 1. Typical performance

Typical RF performance at $T_{case} = 25\text{ °C}$ in a common source class-AB production test circuit.

Mode of operation	f (MHz)	I_{Dq} (mA)	V_{DS} (V)	$P_{L(AV)}$ (W)	G_p (dB)	η_D (%)	ACPR _{885k} (dBc)	ACPR _{5M} (dBc)
IS-95	2500 to 2700	720	28	16	18.5	29	-46 ^[1]	-
Single carrier W-CDMA	2500 to 2700	720	28	25	18.5	35	-	-36 ^[2]

[1] Single carrier IS-95 with pilot, paging, sync and 6 traffic channels (Walsh codes 8 - 13). PAR = 9.7 dB at 0.01 % probability on the CCDF. Channel bandwidth is 1.2288 MHz.

[2] 3GPP; test model 1; 64 DPCH; PAR = 7.2 dB at 0.01 % probability on CCDF. Channel bandwidth is 3.84 MHz.

1.2 Features and benefits

- Excellent ruggedness
- High efficiency
- Low R_{th} providing excellent thermal stability
- Designed for broadband operation (2500 MHz to 2700 MHz)
- Lower output capacitance for improved performance in Doherty applications
- Designed for low memory effects providing excellent pre-distortability
- Internally matched for ease of use
- Integrated ESD protection
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

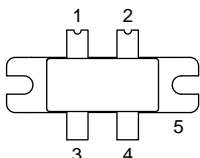
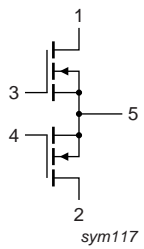
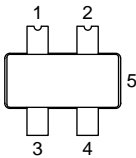
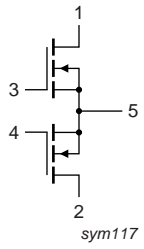
1.3 Applications

- RF power amplifiers for W-CDMA base stations and multi carrier applications in the 2500 MHz to 2700 MHz frequency range



2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
BLF7G27L-90P (SOT1121A)			
1	drain1		 sym117
2	drain2		
3	gate1		
4	gate2		
5	source		
BLF7G27LS-90P (SOT1121B)			
1	drain1		 sym117
2	drain2		
3	gate1		
4	gate2		
5	source		

[1] Connected to flange.

3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BLF7G27L-90P	-	flanged LDMOST ceramic package; 2 mounting holes; 4 leads	SOT1121A
BLF7G27LS-90P	-	earless flanged LDMOST ceramic package; 4 leads	SOT1121B

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage		-	65	V
V_{GS}	gate-source voltage		-0.5	+13	V
I_D	drain current		-	18	A
T_{stg}	storage temperature		-65	+150	°C
T_j	junction temperature		-	225	°C

5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Typ	Unit
$R_{th(j-c)}$	thermal resistance from junction to case	$T_{case} = 80\text{ °C}; P_L = 16\text{ W}$	0.4	K/W

6. Characteristics

Table 6. Characteristics

$T_j = 25\text{ °C}$; per section unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{(BR)DSS}$	drain-source breakdown voltage	$V_{GS} = 0\text{ V}; I_D = 0.6\text{ mA}$	65	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	$V_{DS} = 10\text{ V}; I_D = 60\text{ mA}$	1.5	1.8	2.3	V
I_{DSS}	drain leakage current	$V_{GS} = 0\text{ V}; V_{DS} = 28\text{ V}$	-	-	1.4	μA
I_{DSX}	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75\text{ V}; V_{DS} = 10\text{ V}$	9.6	11.5	-	A
I_{GSS}	gate leakage current	$V_{GS} = 11\text{ V}; V_{DS} = 0\text{ V}$	-	-	150	nA
g_{fs}	forward transconductance	$V_{DS} = 10\text{ V}; I_D = 60\text{ mA}$	-	0.53	-	S
$R_{DS(on)}$	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75\text{ V}; I_D = 2100\text{ mA}$	-	0.24	-	Ω

7. Test information

Table 7. Functional test information

Mode of operation: 1-carrier N-CDMA, single carrier IS-95 with pilot, paging, sync and 6 traffic channels (Walsh codes 8 - 13). PAR = 9.7 dB at 0.01 % probability on the CCDF; channel bandwidth is 1.2288 MHz; $f_1 = 2500\text{ MHz}$; $f_2 = 2700\text{ MHz}$; RF performance at $V_{DS} = 28\text{ V}$; $I_{Dq} = 720\text{ mA}$; $T_{case} = 25\text{ °C}$; 2 sections combined unless otherwise specified; in a class-AB production test circuit.

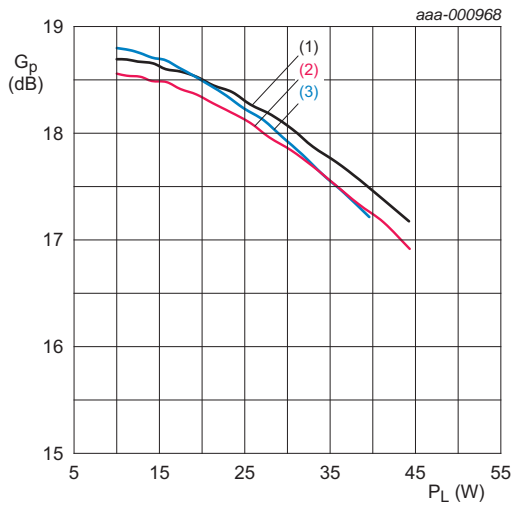
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$P_{L(AV)}$	average output power		-	16	-	W
G_p	power gain	$P_{L(AV)} = 16\text{ W}$	17	18.5	-	dB
RL_{in}	input return loss	$P_{L(AV)} = 16\text{ W}$	-	-15	-	dB
η_D	drain efficiency	$P_{L(AV)} = 16\text{ W}$	25	29	-	%
$ACPR_{885k}$	adjacent channel power ratio (885 kHz)	$P_{L(AV)} = 16\text{ W}$	-	-46	-41	dBc

7.1 Ruggedness in class-AB operation

The BLF7G27L-90P and BLF7G27LS-90P are capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions: $V_{DS} = 28\text{ V}$; $I_{Dq} = 720\text{ mA}$; $P_L = 90\text{ W (CW)}$; $f = 2500\text{ MHz}$.

7.2 Single carrier IS-95

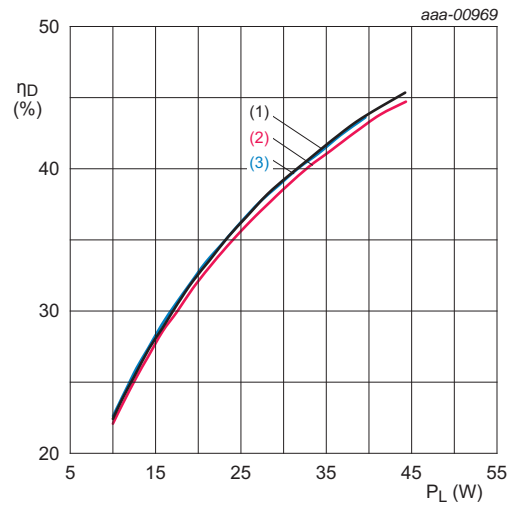
Single carrier IS-95 with pilot, paging, sync and 6 traffic channels (Walsh codes 8 - 13).
 PAR = 9.7 dB at 0.01 % probability on the CCDF. Channel bandwidth is 1.2288 MHz.



$V_{DS} = 28\text{ V}; I_{Dq} = 720\text{ mA}$.

- (1) $f = 2500\text{ MHz}$
- (2) $f = 2600\text{ MHz}$
- (3) $f = 2700\text{ MHz}$

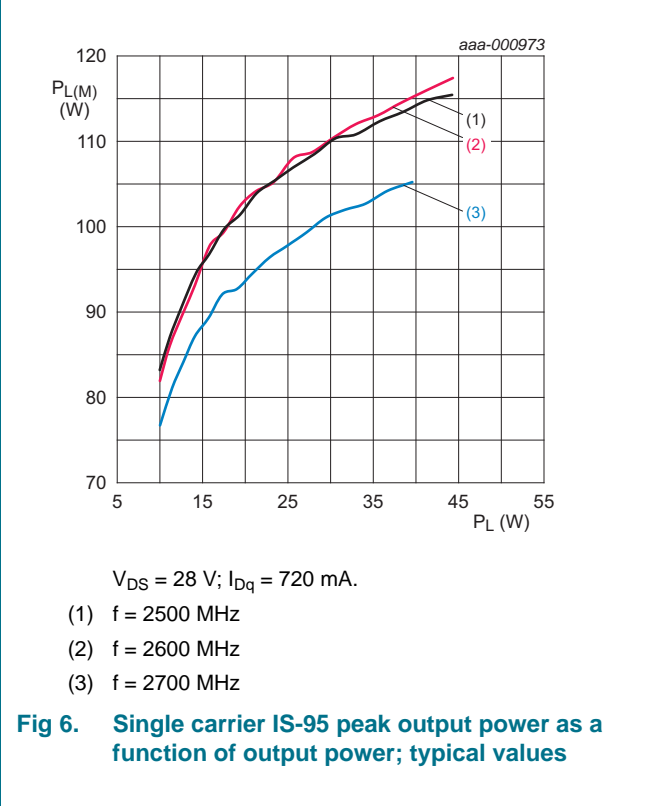
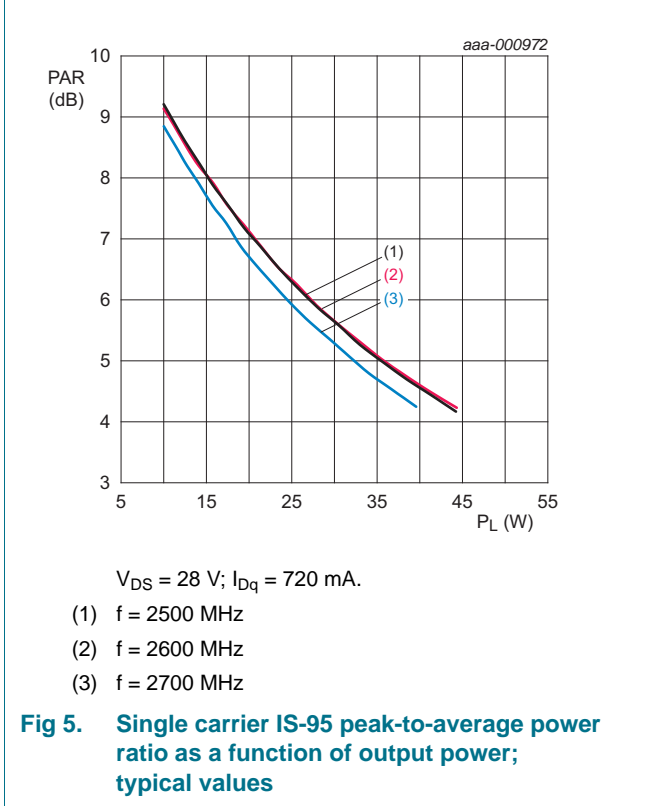
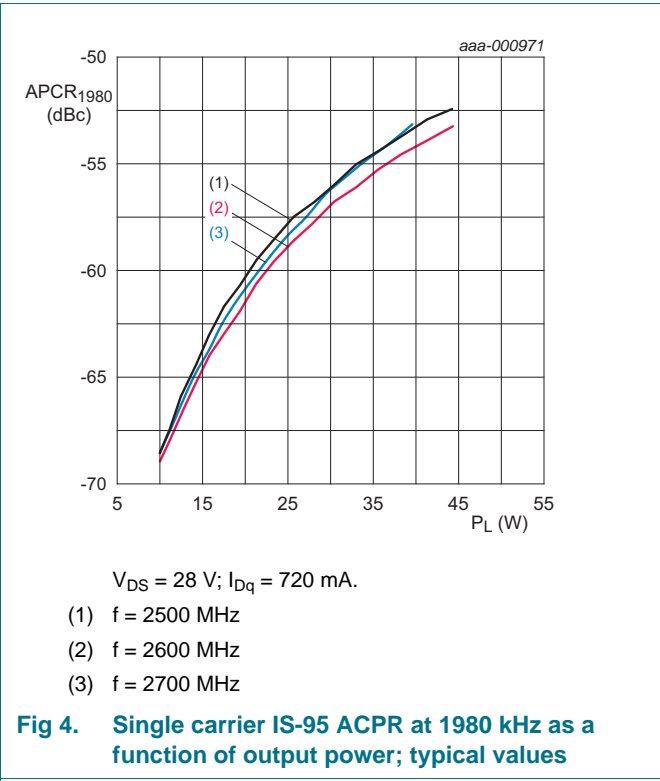
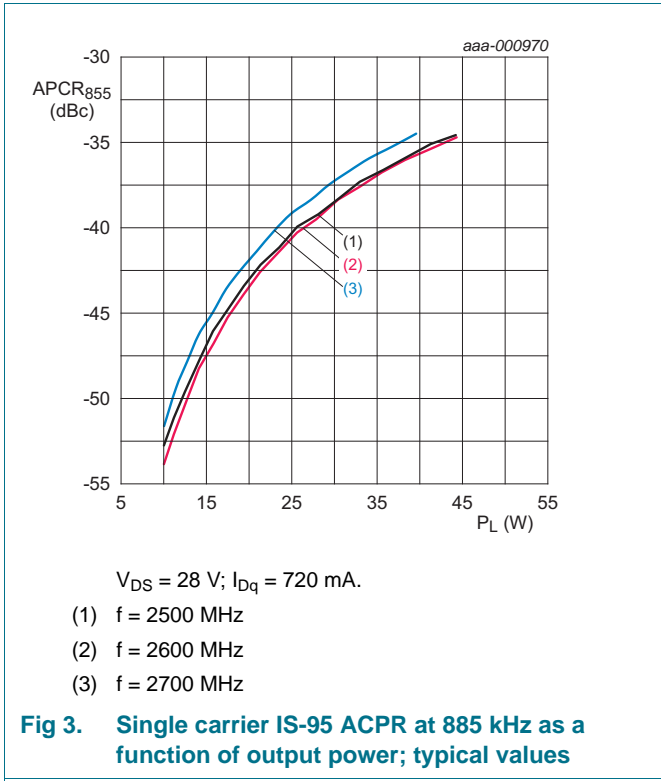
Fig 1. Single carrier IS-95 power gain as a function of output power; typical values



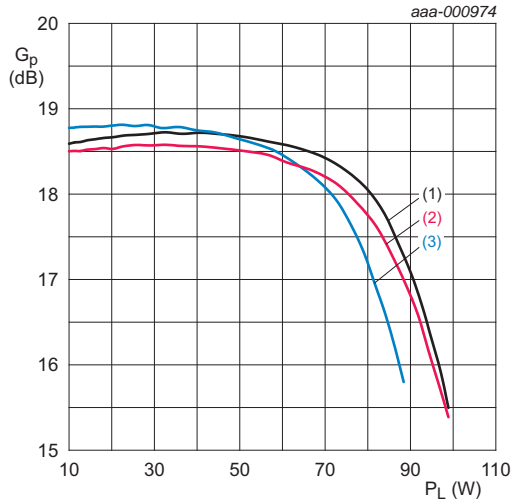
$V_{DS} = 28\text{ V}; I_{Dq} = 720\text{ mA}$.

- (1) $f = 2500\text{ MHz}$
- (2) $f = 2600\text{ MHz}$
- (3) $f = 2700\text{ MHz}$

Fig 2. Single carrier IS-95 drain efficiency as a function of output power; typical values

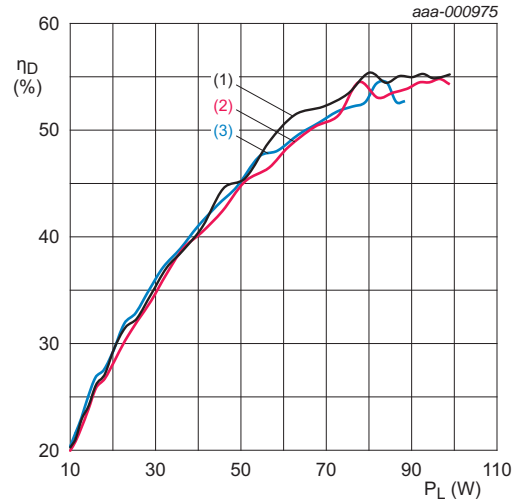


7.3 Pulsed CW



$V_{DS} = 28\text{ V}; I_{Dq} = 720\text{ mA}.$
 (1) $f = 2500\text{ MHz}$
 (2) $f = 2600\text{ MHz}$
 (3) $f = 2700\text{ MHz}$

Fig 7. Pulsed CW power gain as a function of output power; typical values

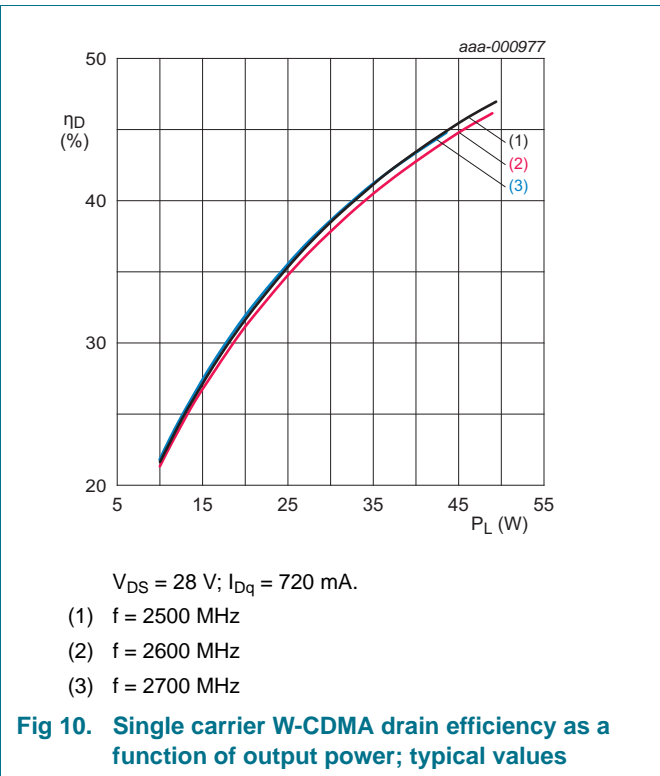
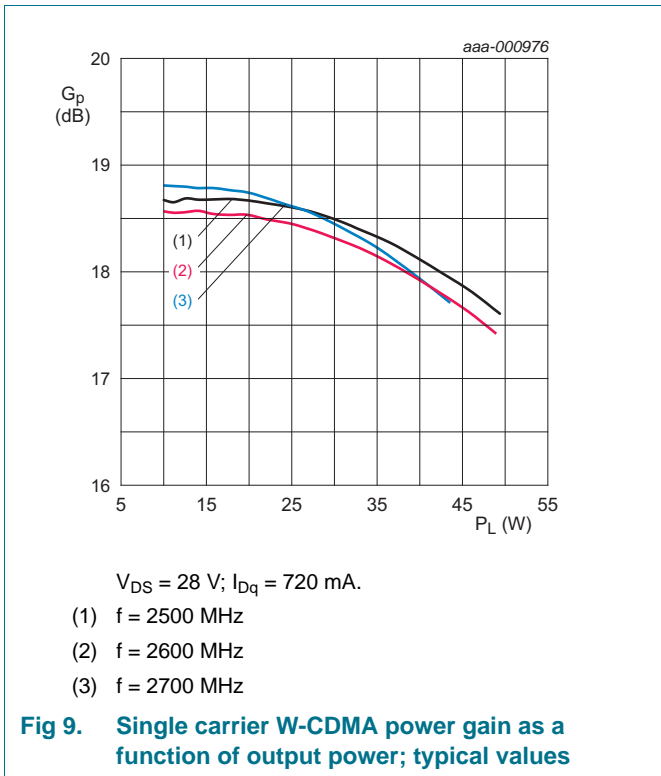


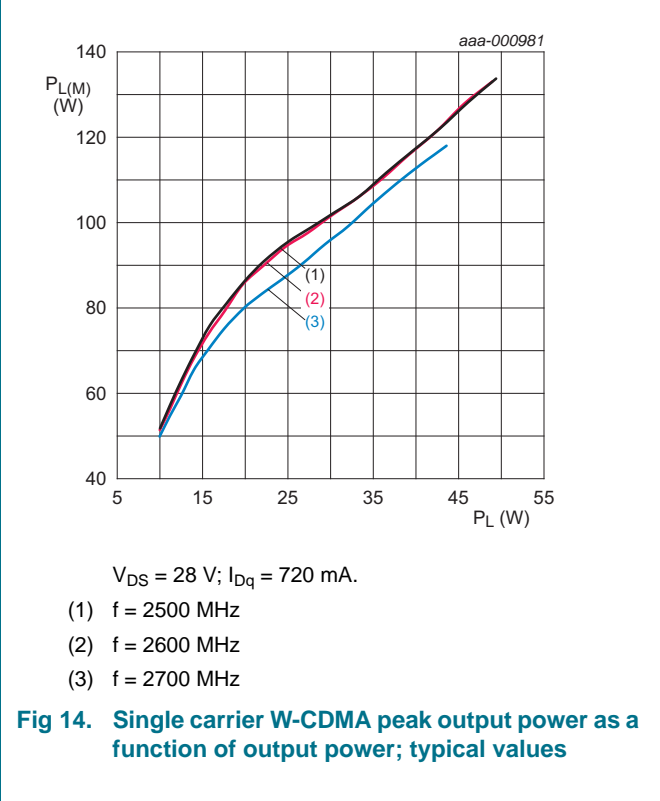
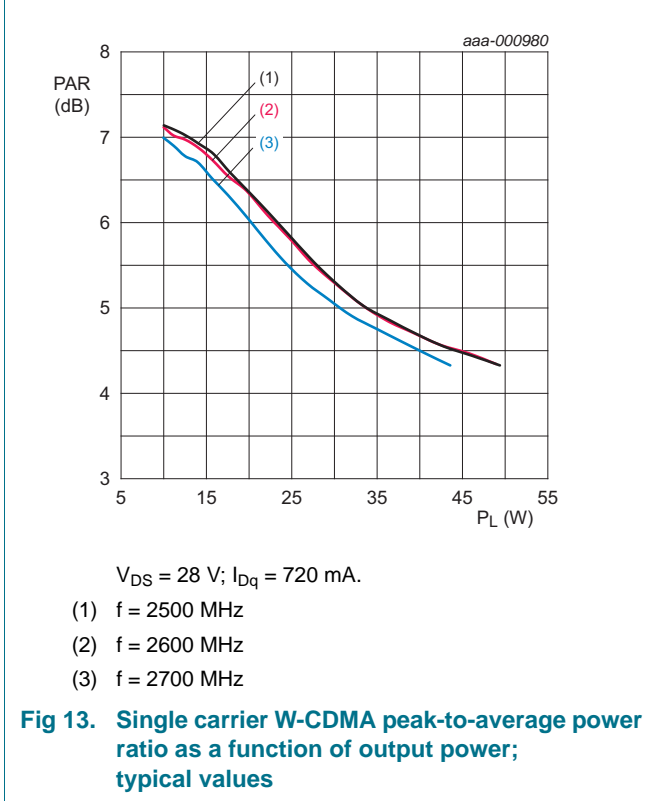
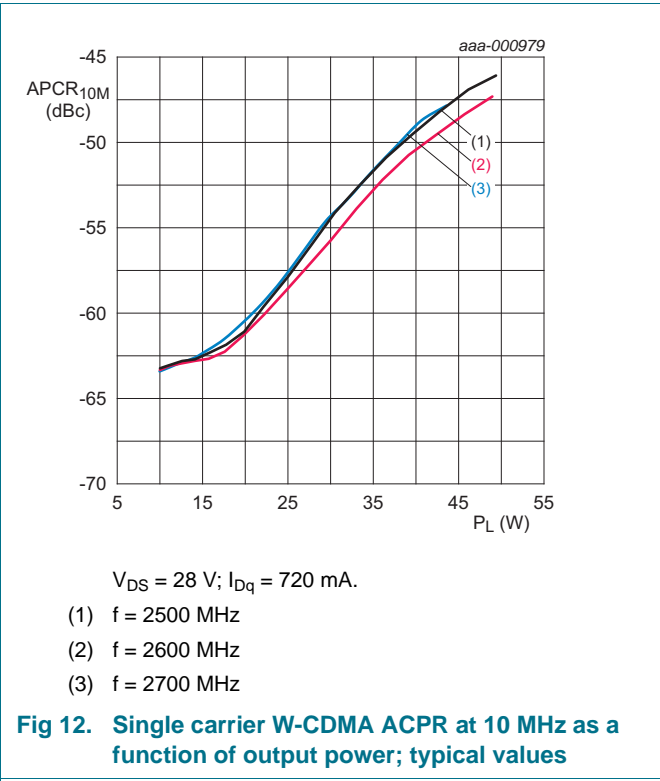
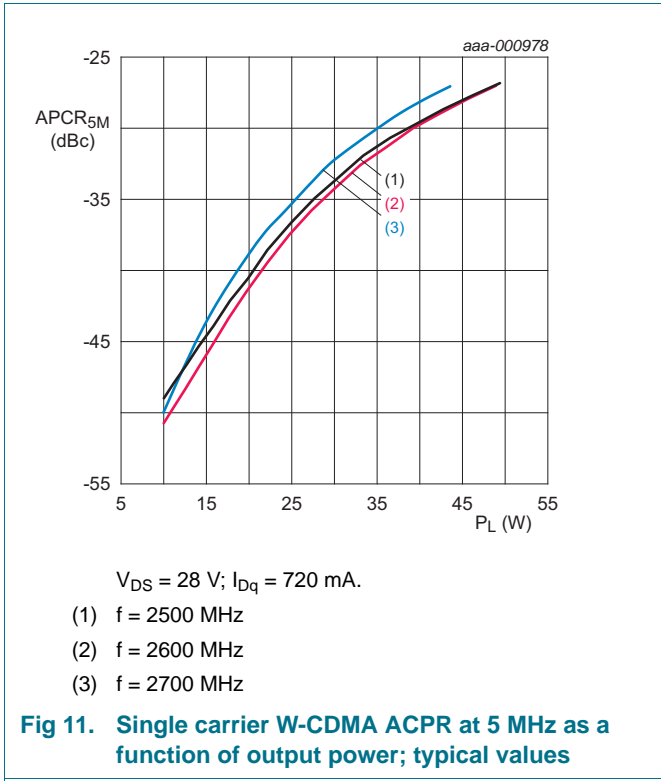
$V_{DS} = 28\text{ V}; I_{Dq} = 720\text{ mA}.$
 (1) $f = 2500\text{ MHz}$
 (2) $f = 2600\text{ MHz}$
 (3) $f = 2700\text{ MHz}$

Fig 8. Pulsed CW drain efficiency as a function of output power; typical values

7.4 Single carrier W-CDMA

3GPP; test model 1; 64 DPCH; PAR = 7.2 dB at 0.01 % probability on CCDF.
Channel bandwidth is 3.84 MHz.





8. Package outline

Flanged LDMOST ceramic package; 2 mounting holes; 4 leads

SOT1121A

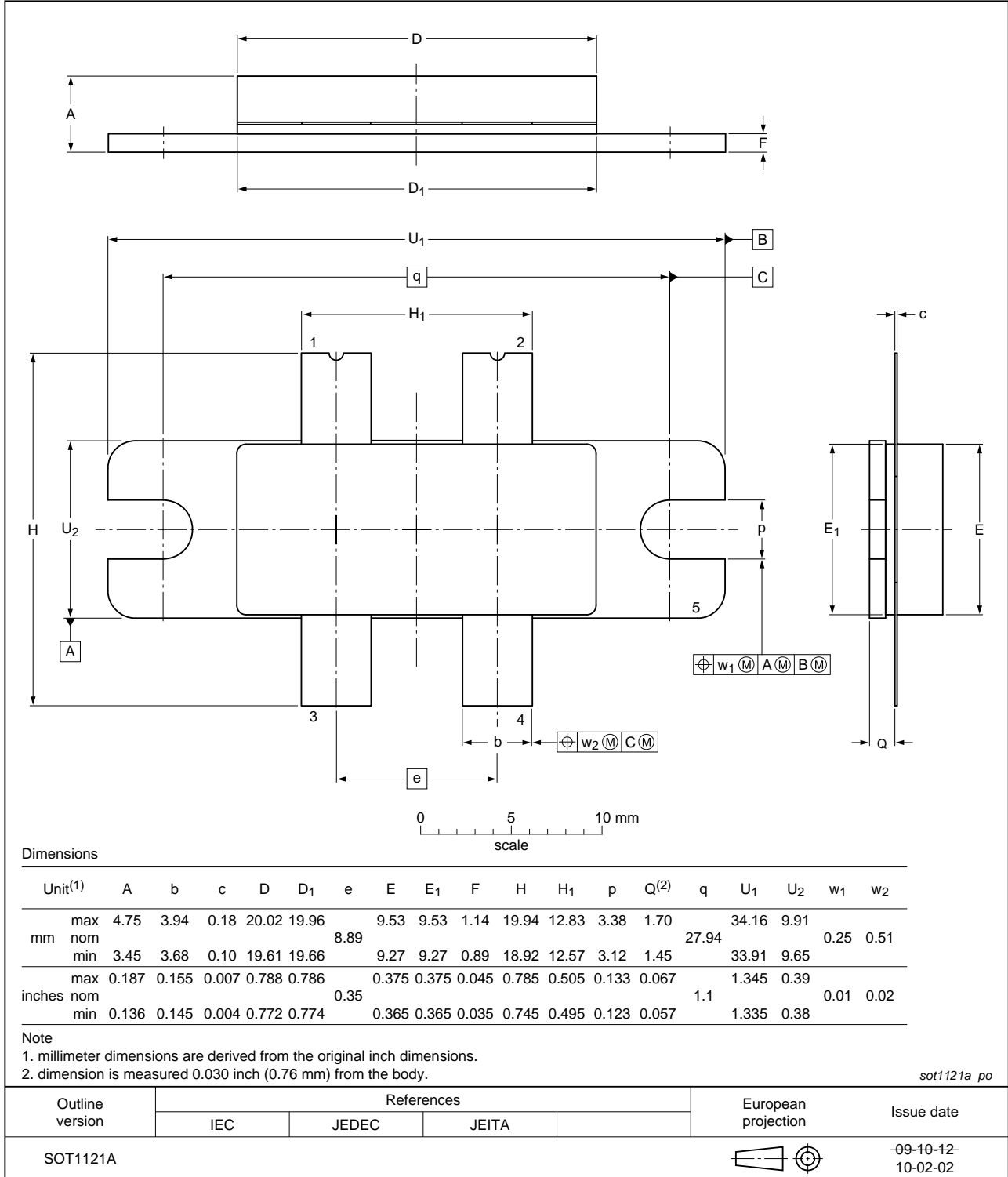


Fig 15. Package outline SOT1121A

Earless flanged LDMOST ceramic package; 4 leads

SOT1121B

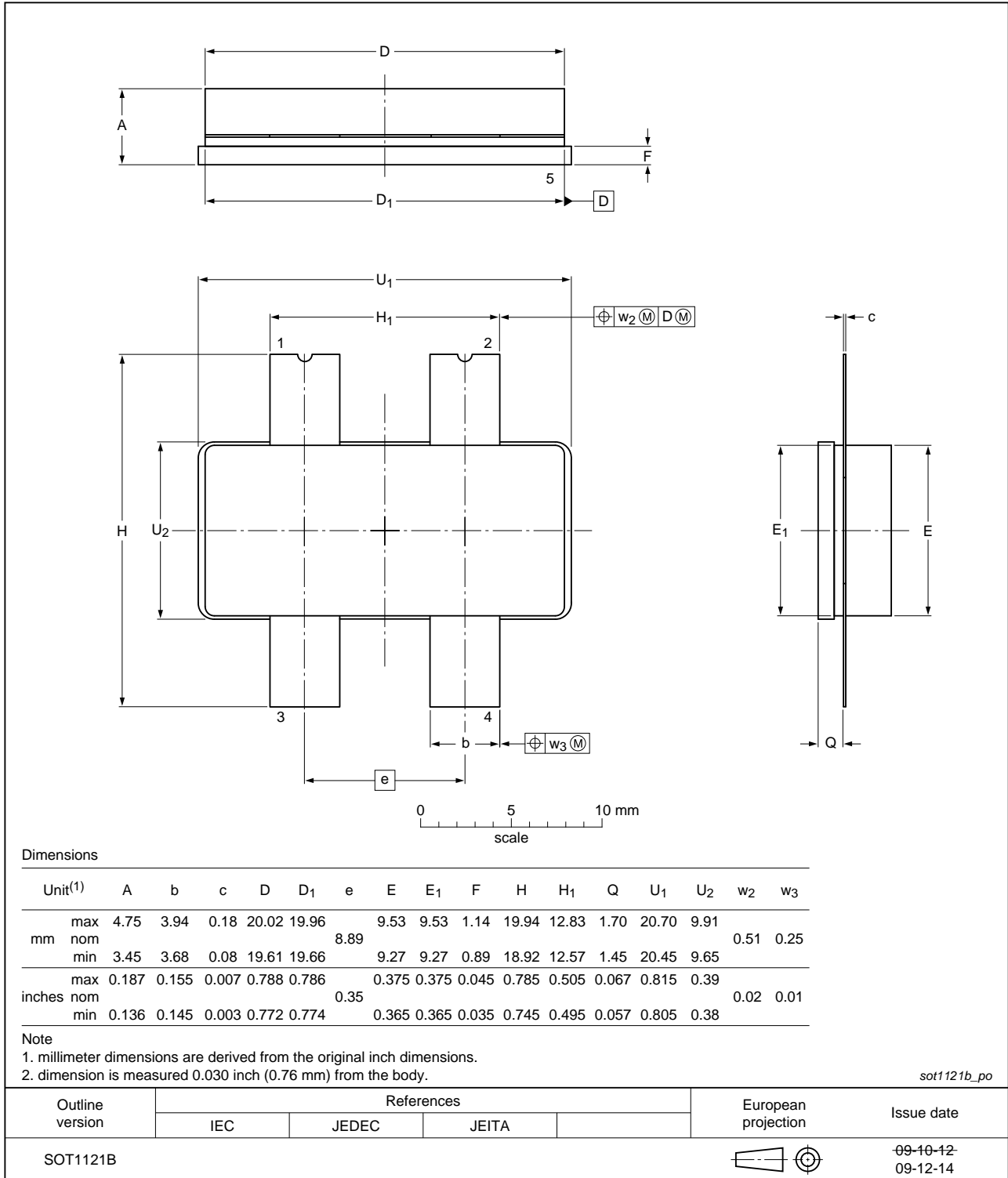


Fig 16. Package outline SOT1121B

9. Abbreviations

Table 8. Abbreviations

Acronym	Description
3GPP	Third Generation Partnership Project
CCDF	Complementary Cumulative Distribution Function
CW	Continuous Wave
DPCH	Dedicated Physical CHannel
IS-95	Interim Standard 95
ESD	ElectroStatic Discharge
LDMOS	Laterally Diffused Metal Oxide Semiconductor
LDMOST	Laterally Diffused Metal Oxide Semiconductor Transistor
N-CDMA	Narrowband Code Division Multiple Access
PAR	Peak-to-Average power Ratio
RF	Radio Frequency
VSWR	Voltage Standing Wave Ratio
W-CDMA	Wideband Code Division Multiple Access

10. Revision history

Table 9. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BLF7G27L-90P_BLF7G27LS-90P v.2	20111110	Product data sheet	-	BLF7G27L-90P_BLF7G27LS-90P v.1
Modifications:				
				<ul style="list-style-type: none"> • Table 1 on page 1: Some values have been changed; added row: Single carrier W-CDMA. • Table 5 on page 3: Some values have been changed. • Table 6 on page 3: Some values have been changed/added. • Table 7 on page 3: Some values have been changed. • Section 7.1 on page 3: Some values have been changed. • Section 7.2 on page 4: Graphs have been added. • Section 7.3 on page 6: Graphs have been added. • Section 7.4 on page 7: Graphs have been added.
BLF7G27L-90P_BLF7G27LS-90P v.1	20101102	Objective data sheet	-	-

11. Legal information

11.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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